

**PH795DBR  
795nm Series**

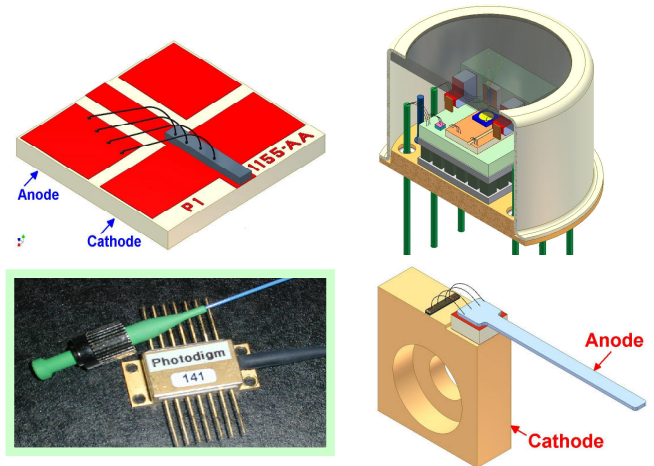
**High-Power Single-Frequency Laser Diode**

**Technology**

- DBR Single-Frequency Laser Chip
- AlGaAs QW Active Layer
- Epi designed for high reliability

**Features**

- Available in several package styles
- Pulsed operation for spectral stability at short pulse lengths
- High power for CW applications
- High Slope Efficiency



**Description**

The PH795DBR Series of high-power edge-emitting lasers are based on Photodigm’s advanced single-frequency laser technology. It provides a diffraction limited, single lateral and longitudinal mode beam. Facets are passivated for high-power reliability. Applications include rubidium-based D1 applications.

**Absolute Maximum Ratings**

Parameter	Symbol	Unit	Min	Max
Storage Temperature	T <sub>STG</sub>	°C	0	80
Operating Temperature	T <sub>OP</sub>	°C	5.0	70
CW Laser Forward Current, T=25°C *	I <sub>F</sub>	mA	-	150**
Pulsed Laser Forward Current, T=25°C, PW=300 ns, DC=10%	I <sub>F</sub>	A	-	0.3
Laser Reverse Voltage	V <sub>R</sub>	V	-	0.0
Photodiode Forward Current <u>1/2/</u>	I <sub>P</sub>	mA	-	5.0
Photodiode Reverse Voltage <u>1/2/</u>	V <sub>R</sub>	V	-	20.0
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, <u>1/2/</u>	I <sub>D</sub>	nA	-	50
TEC Current <u>1/2/</u>	I <sub>TEC</sub>	A	-2.0	2.0
TEC Voltage <u>1/2/</u>	V <sub>TEC</sub>	V	-6.0	6.0
Thermistor Current <u>1/2/</u>	I <sub>THRM</sub>	mA	-	1.0
Thermistor Voltage <u>1/2/</u>	V <sub>THRM</sub>	V	-	10
External Back Reflection	-	dB	-	-14
Lead Soldering Temperature, 10 sec. Max. <u>1/2/</u>	-	°C	-	260
Fiber Pull Force <u>1/</u>	-	N	-	5.0
Fiber Bend Radius <u>1/</u>	-	mm	-	35

1/ Butterfly package 2/ TO8 package

\* unless otherwise noted

\*\* drive current of supplied LIV shall apply

**CW Characteristics at T<sub>c</sub> = 25°C unless otherwise specified**

Parameter	Symbol	Unit	Min	Typ	Max
Center Wavelength @ 150mA	$\lambda_c$	nm	793	795	797
Optical Output Power @ 150mA	$P_o$	mW	See Power Options Call-out		
Slope Efficiency, 1/	$\eta_d$	W/A	0.3	0.36	
Slope Efficiency	$\eta_d$	W/A	0.6	0.75	-
Threshold Current	$I_{th}$	mA	-	50	70*
Laser Series Resistance	$R_S$	$\Omega$	-	4.0	4.5
Laser Forward Voltage @ 150mA	$V_F$	V	-	2.0	2.5
Thermistor Resistance @ 25°C, 1/2/	$R_T$	K $\Omega$	-	10	-
Photodiode Dark Current, V <sub>R</sub> =10V, LD I <sub>F</sub> =0, 1/2/	$I_D$	nA	-	-	50
Laser Line Width @ 150mA	$\Delta\nu$	MHz	-	0.7	1.0
Polarization Extinction Ratio, 1/	PER	dB	-16	-19	-
Beam Divergence @ FWHM	$\theta_{  } \times \theta_{\perp}$	°	-	6 X 26	8 X 28
Side Mode Suppression Ratio	SMSR	dB	-30	-	-
Laser Polarization				TE	
Mode Structure			Fundamental Mode		

1/ Butterfly package 2/ TO-8 package

\*standard ridge device

**Handling Precautions**

These devices are sensitive to ESD. When handling the module, grounded work area and wrist strap must be used. Always store in an antistatic container with all leads shorted together.

**How To Order**

Part number example: PH795DBR080CM. Assign optical power from those available shown in Photodigm's Product Capabilities Brochure. Use a three-digit format for all power entries. Call factory for special frequency selection and certification to certain atomic absorption lines.

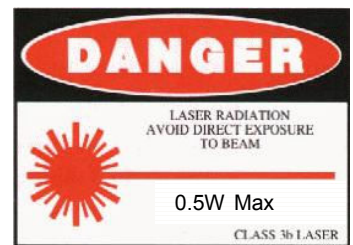
PH795DBR 

**Minimum Power (mW)**

**040 060**  
**080**

**Package Type**

**CS** Chip on Submount  
**CM** 'C' Mount  
**BF** Butterfly  
**T8** TO-8



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